

Features

- Split Gate Trench MOSFET Technology
- · Excellent Stability And Uniformity
- · Moisture Sensitivity Level 3
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

P-CHANNEL MOSFET

Maximum Ratings

- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 56.8°C/W Junction to Ambient(Note 2)

Parameter	Symbol	Rating	Unit		
Drain-Source Voltage		V _{DS}	-100	V	
Gate-Source Volltage		V_{GS}	±20	V	
Continuous Drain Current	T _A =25°C		-8	Α	
	T _A =100°C	– I _D	-5		
Pulsed Drain Current (Note3)		I _{DM}	-32	Α	
Total Power Dissipation (Note4)		P _D	2.2	W	

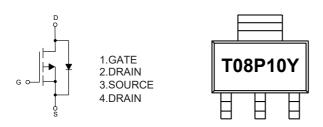
Note:

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The Value of $R_{\theta JA}$ is Measured with the Device Mounted on 1in2 FR-4 Board with 1oz. Copper, in a Still Air Environment with T_A =25°C.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

SOT-223

DIMENSIONS					
DIM	INC	INCHES		М	NOTE
DIIVI	MIN	MAX	MIN	MAX	NOTE
Α	0.248	0.264	6.30	6.70	
В	0.130	0.146	3.30	3.70	
С	0.264	0.287	6.70	7.30	
D	0.001	0.004	0.02	0.10	
Е	0.114	0.122	2.90	3.10	
F	0.091		2.30		TYP.
G		0.071		1.80	
Н	0.009	0.014	0.23	0.35	
J	0.030		0.75		
K	0.026	0.033	0.66	0.84	

⇒bhYfbU Ghfi Wi fY UbX A Uf_]b[7 cXY





Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics	-1					I	
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-250μA	-100			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-100V, V _{GS} =0V			-1	μA	
		V _{DS} =-100V, V _{GS} =0V, T _J =55°C			-5	μA	
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-1	-1.8	-2.5	V	
Drain-Source On-Resistance	Б	V _{GS} =-10V, I _D =-8A	95 110		110		
	$R_{DS(on)}$	V _{GS} =-4.5V, I _D =-5A		103	130	mΩ	
Gate Resistance	R _g	f=1 MHz, Open drain		9.5		Ω	
Diode Characteristics			<u> </u>				
Continuous Body Diode Current	Is				-8	Α	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =-8A		-0.9	-1.3	V	
Reverse Recovery Time	t _{rr}	I _s =-5A,di/dt=100A/μs		38		ns	
Reverse Recovery Charge	Q _{rr}	1837,41/41-1007/µ3		70		nC	
Dynamic Characteristics							
Input Capacitance	C _{iss}			1080			
Output Capacitance	C _{oss}	V _{DS} =-80V,V _{GS} =0V,f=1MHz		93		pF	
Reverse Transfer Capacitance	C _{rss}			9			
Total Gate Charge	Q_g			20			
Gate-Source Charge	Q_{gs}	V_{DS} =-50V, V_{GS} =-10V, I_{D} =-5A		2.9		nC	
Gate-Drain Charge	Q_{gd}			3.5			
Turn-On Delay Time	t _{d(on)}			7			
Turn-On Rise Time	t _r	V _{GS} =-10V,V _{DD} =-50V,		14			
Turn-Off Delay Time	t _{d(off)}	I_{DS} =-20A, R_{GEN} =6 Ω		43		- ns	
Turn-Off Fall Time	t _f			35			



Curve Characteristics

Fig.1 - Typical Output Characteristics

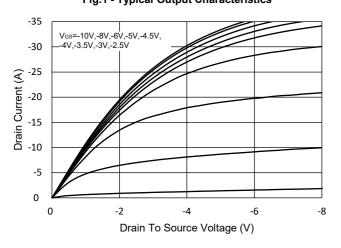


Fig.2 - Transfer Characteristic

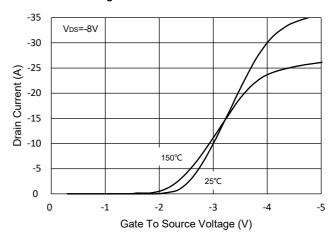


Fig.3 - $R_{\rm DS(ON)}$ - $V_{\rm GS}$

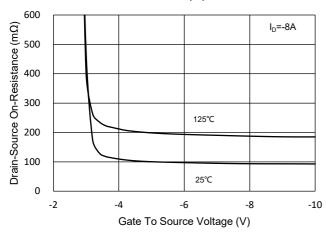


Fig.4 - R_{DS(ON)} - I_D

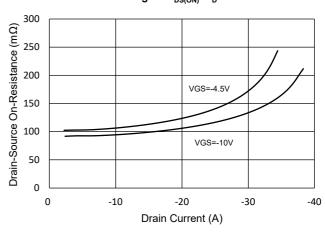


Fig.5 - Capacitance Characteristics

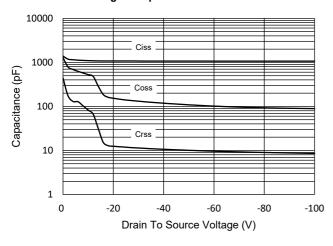
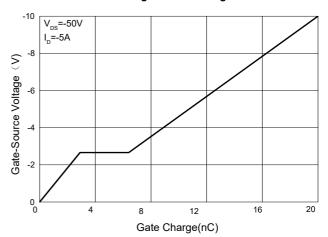
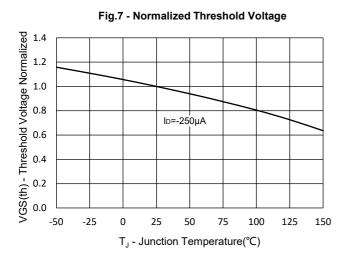


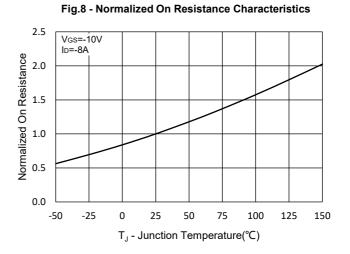
Fig. 6 - Gate Charge

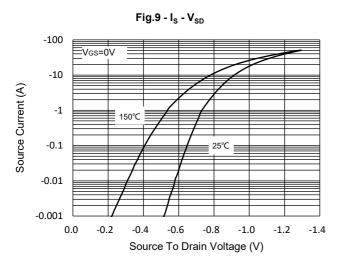


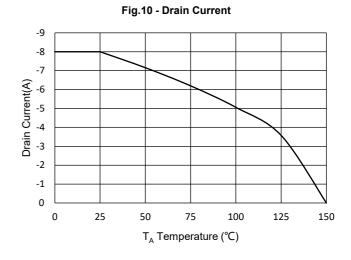


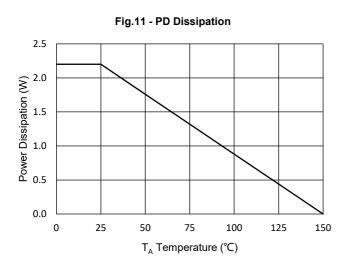
Curve Characteristics





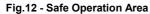








Curve Characteristics



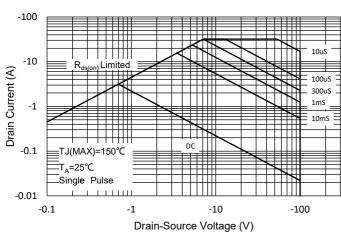
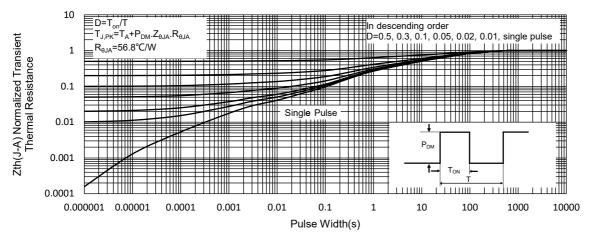


Fig.13 - Normalized Transient Thermal Impedance





Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel

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